

Switch Mode Secondary Side Post Regulator

FEATURES

- Precision Secondary Side Post Regulation for Multiple Output Power Supplies
- Useful for Both Single Ended and Center Tapped Secondary Circuits
- Ideal Replacement for Complex Magnetic Amplifier Regulated Circuits
- Leading Edge Modulation
- Does Not Require Gate Drive Transformer
- High Frequency (>500kHz) Operation
- Applicable for Wide Range of Output Voltages
- High Current Gate Driver (0.5A Sink/1.5A Source)
- Average Current Limiting Loop

DESCRIPTION

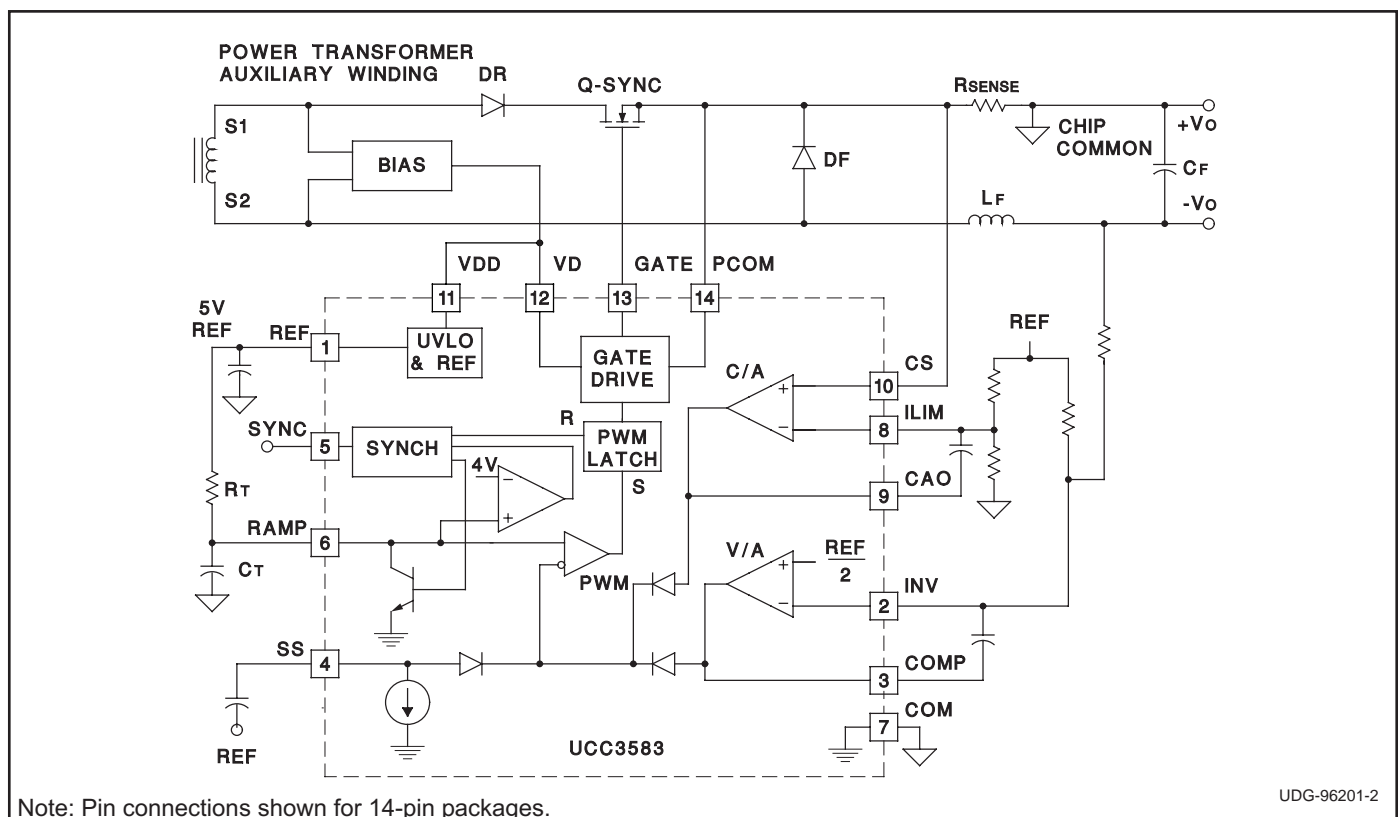
The UCC3583 is a synchronizable secondary side post regulator for precision regulation of the auxiliary outputs of multiple output power supplies. It contains a leading edge pulse width modulator, which generates the gate drive signal for a FET power switch connected in series with the rectifying diode. The turn-on of the power switch is delayed from the leading edge of the secondary power pulse to regulate the output voltage. The UCC3583 contains a ramp generator slaved to the secondary power pulse, a voltage error amplifier, a current error amplifier, a PWM comparator and associated logic, a gate driver, a precision reference, and protection circuitry.

The ramp discharge and termination of the gate drive signal are triggered by the synchronization pulse, typically derived from the falling edge of the transformer secondary voltage. The ramp starts charging again once its low threshold is reached. The gate drive signal is turned on when the ramp voltage exceeds the control voltage. This leading edge modulation technique prevents instability when the UCC3583 is used in peak current mode primary controlled systems.

The controller operates from a floating power supply referenced to the output voltage being controlled. It features an undervoltage lockout (UVLO) circuit, a soft start circuit, and an averaging current limit amplifier. The current limit can be programmed to be proportional to the output voltage, thus achieving foldback operation to minimize the dissipation under short circuit conditions.

(continued)

TYPICAL APPLICATION AND BLOCK DIAGRAM



UDG-96201-2

ABSOLUTE MAXIMUM RATINGS

V _{DD}	15V
I _{VDD}	15mA
RAMP	−0.3V to V _{DD} + 1V
I _{RAMP}	5mA
I _{REF}	−30mA
PCOM	−0.2V to 0.2V
I _{GATE} (t _{wp} < 1μS and Duty Cycle < 10%)	−0.8A to 1.8A
I _{COMP}	−5mA to 5mA
I _{CAO}	−5mA to 5mA
V _{SYNC}	−0.6V to V _{REF} + 0.3V
I _{SYNC}	−05mA to 5mA
INV, SS, ILIM, ISENSE	−0.3V to V _{REF} + 0.3V
Storage Temperature	−65°C to +150°C
Junction Temperature	−55°C to +150°C
Lead Temperature (Soldering, 10 sec.)	+300°C

All voltages are with respect to the COM terminal unless otherwise stated. Currents are positive into, negative out of the specified terminal. Consult Packaging Section of Databook for thermal limitations and considerations of packages.

THERMAL IMPEDANCE

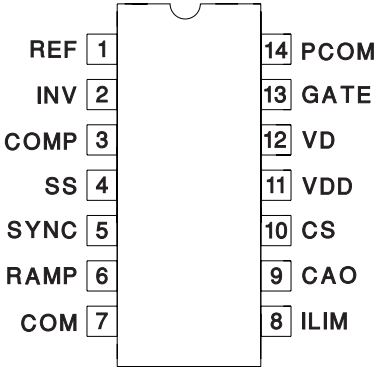
PACKAGE	θ _{ja}	θ _{jc}
N-14	90	45
J-14	90-120	28
D-14	50-120	35
PLCC-20	43-75	34

Note 1. θ_{ja} (junction to ambient) is for devices mounted to 5 in2 FR4 PC board with one ounce copper where noted. When resistance range is given, lower values are for 5 in2 aluminum PC board. Test PWB was .062 in thick and typically used 0.635 mm trace widths for power pkgs and 1.3 mm trace widths for non-power pkgs with a 100x100 mil probe land area at the end of each trace

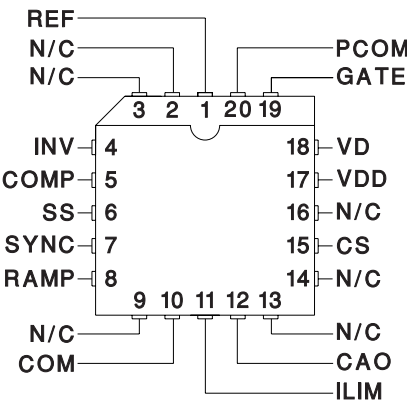
Note 2. q_{jc} data values stated were derived from MIL-STD-1835B. MIL-STD-1835B states that “The baseline values shown are worst case (mean + 2s) for a 60x60 mil microcircuit device silicon die and applicable for devices with die sizes up to 14400 square mils. For device die sizes greater than 14400 square mils use the following values; dual-in-line, 11°C/W; flat pack, 10°C/W; pin grid array, 10°C/W”.

CONNECTION DIAGRAMS

DIL-14, SOIC-14 (Top View)
J, N, or D Packages



PLCC-20 (Top View)
Q Package



ELECTRICAL CHARACTERISTICS: Unless otherwise stated, these specifications apply for T_A = −55°C to 125°C for UCC1583, −40°C to 85°C for UCC2583, and 0°C to 70°C for UCC3583; V_{DD} = 12V, R_T = 60k, C_T = 100pF, T_A = T_J.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Ramp Generation and Synchronization					
Maximum Input Operating Frequency	For input with 5% to 90% duty cycle (Note 1)	500			kHz
Ramp Frequency, Free Running	T _A = 25°C	95	100	105	kHz
	T _A = −55°C to 125°C	90	100	110	kHz
Ramp Discharge Current	V _{RAMP} = 0.5V	2.0	3.6		mA
Low Threshold Voltage	No min, no max, 0=TYP		0		V
High Threshold Voltage		3.75	4	4.25	V
Synchronizing Threshold Voltage (On)	(Note 1)		1		V
Synchronizing Comparator Hysteresis			1		V

ELECTRICAL CHARACTERISTICS: Unless otherwise stated, these specifications apply for $T_A = -55^{\circ}\text{C}$ to 125°C for UCC1583, -40°C to 85°C for UCC2583, and 0°C to 70°C for UCC3583; $V_{DD} = 12\text{V}$, $R_T = 60\text{k}$, $C_T = 100\text{pF}$, $T_A = T_J$.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Output Duty Cycle					
Minimum Duty Cycle	Output D/C = Output PW / Input PW			0	%
Maximum Duty Cycle	Output D/C = Output PW / Input PW	100			%
Voltage Error Amplifier					
V_{INV}	$V_{COMP} = V_{INV}$, 0°C to 70°C (UCC3583)	2.462	2.5	2.538	V
	$V_{COMP} = V_{INV}$, All Other Temperature Ranges	2.45	2.5	2.55	V
I_{INV}	$V_{COMP} = V_{INV}$		300	500	nA
V_{COMP} Low	$V_{INV} = 2.6\text{V}$, $I_{COMP} = 100\mu\text{A}$		450	700	mV
V_{COMP} High	$V_{INV} = 2.4\text{V}$, $I_{COMP} = -100\mu\text{A}$	5.0	5.5	6.0	V
AVOL	No Load	70	90		dB
GBW Product	At $f = 100\text{kHz}$, $T_A = 25^{\circ}\text{C}$ (Note 1)	3	5		MHz
Current Error Amplifier					
Input Offset Voltage				10	mV
Input CM Low	Common Mode for CS and ILIM (Note 1)			0	V
Input CM High	Common Mode for CS and ILIM (Note 1)	2			V
V_{CAO} Low	$V_{+IN} = 0\text{V}$, $V_{-IN} = 0.1\text{V}$, $I_{CAO} = 100\mu\text{A}$		250	500	mV
V_{CAO} High	$V_{+IN} = 0\text{V}$, $V_{-IN} = 0.1\text{V}$, $I_{CAO} = -100\mu\text{A}$	5.0	5.5	6.0	V
Input Current (ILIM and CS Pins)		-50	0	50	nA
AVOL	No Load	70	90		dB
GBW Product	At $f = 100\text{kHz}$, $T_A = 25^{\circ}\text{C}$	2	4		MHz
Soft Start Current			10	25	μA
UVLO					
VDD On Threshold Voltage		8.5	9.0	9.5	V
VDD Off Threshold Voltage		7.9	8.4	8.9	V
UVLO Hysteresis		0.3	0.6	0.9	V
Bias Supply					
Supply Clamp Voltage		13	14	15	V
Supply Current (VDD)	$f = 100\text{kHz}$ With No Gate Output Load		3	5	mA
Output Driver					
V_{SAT} High	$I_{GATE} = -150\text{mA}$		0.6	1.0	V
V_{SAT} Low	$I_{GATE} = 50\text{mA}$		0.4	0.75	V
Rise Time	$C_{GATE} = 1\text{nF}$		50	75	ns
Fall Time	$C_{GATE} = 330\text{pF}$		20	40	ns
Reference					
V_{REF}	$I_{REF} = 0$, 0°C to 70°C (UCC3583)	4.925	5	5.075	V
	$I_{REF} = 0$, All Other Temperature Ranges	4.900	5	5.100	V
Line Regulation	$V_{DD} = 10\text{V}$ to 14V		2	30	mV
Load Regulation	$I_{REF} = 0\text{mA}$ to 2mA		1	20	mV

Note 1: Ensured by design. Not 100% tested in production.

PIN DESCRIPTIONS

CAO: Output of the current error amplifier. Averaging of the sensed current signal is provided by connecting an integrating capacitor between ILIM and CAO. CAO feeds into the PWM comparator input and controls the loop when its voltage is higher than the voltage at COMP (output of the voltage error amplifier).

COM: Signal ground for the chip. It is connected to the positive terminal of the output voltage being regulated by the IC.

COMP: Output of the voltage error amplifier fed into the PWM comparator. Loop compensation components are connected between COMP and INV.

CS: Non-inverting input of the current error amplifier. The sensed current signal from the current sense resistor is connected to this pin. By making the signal at CS proportional to the output voltage, effective current foldback limiting can be provided.

GATE: Gate drive output for the power switch FET. The drive pin has a 0.5A sink/1.5A source capability and very low output off-state impedance.

ILIM: Inverting input of the current error amplifier. It sets the DC limit for the output current.

INV: Inverting input of the voltage error amplifier. The feedback signal is connected to this pin using a resistive divider between REF and $-V_o$.

PCOM: Power ground for the chip. It is connected to the source terminal of the MOSFET being regulated by the IC.

RAMP: This pin is the input to the PWM comparator and provides a ramp signal for generation of the PWM signal. A capacitor to COM and a resistor to REF set the charging rate for the ramp. An internal current source of

1mA discharges RAMP when synchronization signal appears or when RAMP crosses a 4V threshold. In the intended mode of operation, the switching frequency is determined by the secondary power pulse. The RC components at RAMP should be selected to give an appropriately sized ramp signal. In the absence of a synchronizing pulse, these RC components determine the free running frequency of the controller.

REF: Precision 5V reference pin. REF stays off until VDD exceeds 9V and turns off again when VDD drops below 8.4V. Bypass REF to COM.

SS: This pin provides a soft start function. A capacitor to REF programs the soft start time. During soft start, the PWM comparator is controlled by the soft start voltage resulting in a slow increase in output duty cycle. Once the soft start capacitor is discharged, output control is dictated by the larger of the output at CAO or COMP.

SYNC: Synchronization input pin. It is connected to a signal representative of the secondary power pulse. One possible implementation is to use a resistive divider between terminal S2 of the secondary winding shown in Figure 1 and REF for generating the input to the SYNC pin. The synchronizing comparator is referenced to 0.5V and has $\pm 500\text{mV}$ of hysteresis. The trip levels are approximate 1.0V and 0.0V. The designer should prevent the SYNC pin from exceeding 0.3V below ground as this will turn on the ESD diode.

VD: Power supply for the output driver. VD should be tied to VDD in the application.

VDD: Power supply for the chip. VDD should be bypassed to COM. VDD has to be 9V for the IC to start and 8.4V for it to remain operational. A shunt clamp from VDD to COM limits the supply voltage to 14V.

APPLICATION INFORMATION

Power Stage Circuit Configuration

The UCC3583 is designed for use in a post regulator application for tightly regulating auxiliary outputs in a multiple output converter. The post regulation is applied to the secondary side power pulse of a power transformer where the power pulse is controlled by the feedback signal from the main output. In order to simplify the application of the UCC3583, it is required that the IC be referenced to the positive output terminal and the output filter inductor be placed in the return path. The placement of the inductor in the return path facilitates better EMI performance, in addition to making magnetic designs

and terminations easier to implement. Typical set-up and circuit waveforms of the UCC3583 system application are shown in Figure 1. Figure 2 shows waveforms for a single ended output rectifier application of the UCC3583 shown on page 1. The UCC3583 can also be used in half bridge rectifier applications as shown by the circuit and waveforms depicted in Figures 3 and 4. Referencing the IC to the positive output terminal creates a requirement for a floating bias voltage for the IC which can be referenced to the same positive voltage terminal. Possible implementations of deriving the floating bias voltage are shown in Figure 5.

APPLICATION INFORMATION (cont.)

For the circuit shown in Figure 5a, CC1 is charged when the transformer voltage is positive and the synchronous switch is on. During the off period of Q-SYNC, the charge is transferred to CC2 through diode DC2. Diode DC3 charges CC2 during the blocking interval of Q-SYNC. This method is preferable when the transformer positive voltage is high enough to generate the required bias voltage. For the circuit shown in Figure 5b, CC1 is charged during the period when reverse (reset) voltage appears across the secondary. The charge on CC1 is transferred to CC2 through DC2 when Q-SYNC turns on. This method is preferable when the reverse voltage is high enough to generate the required bias voltage. The series resistor should be chosen to handle the required voltage drop at full IC operating current when the zener clamp across VDD and COM is activated.

The following is a description of the major functional blocks of the UCC3583. Refer to Figure 6 (Typical Application Circuit) for component designations.

UVLO and Start Up

The UCC3583 has an internal undervoltage lockout circuit which keeps the internal circuitry inactive until VDD exceeds the upper threshold (9V). Once the chip is activated, VDD has to be above the lower UVLO threshold (8.4V) for it to remain functional. The IC requires a low startup current of only 100µA when VDD is under the UVLO threshold. VDD has an internal clamp of 14V which can sink up to 10mA. Measures must be taken not to exceed this current. The internal reference (REF) is brought up when the UVLO on threshold is exceeded.

The soft start pin provides an effective means to start the IC in a controlled manner. An internal current of 10µA starts discharging a capacitor connected to SS when the UVLO conditions have been removed. The voltage on SS controls the duty cycle of the output during the discharge period.

Synchronizing Circuit and Oscillator

UCC3583 is primarily intended for synchronizable operation where its switching frequency is determined by the secondary pulse of the power transformer. However, it has an internal oscillator which allows it to operate in free-running mode when an external synchronization pulse is not available. The switching frequency is determined by resistor RT connected between REF and RAMP and capacitor CT connected from RAMP to GND. The frequency is given by:

$$freq = \frac{1}{t_{CH} + t_{DIS}} \text{ where } t_{CH} = 1.56 \cdot R_T \cdot C_T$$

and

$$t_{DIS} = \frac{C_T \cdot V_{RAMP(p-p)}}{I_{RAMP(dis)}} \approx 3000 \cdot C_T$$

The values of RT and CT are also dictated by the fact that the ramp is discharged through an internal impedance of 2k. The value of RT needs to be at least 50k to ensure that the internal discharge current is the current through RT during the entire discharge period. This results in making the value of CT relatively small for a desired frequency of operation.

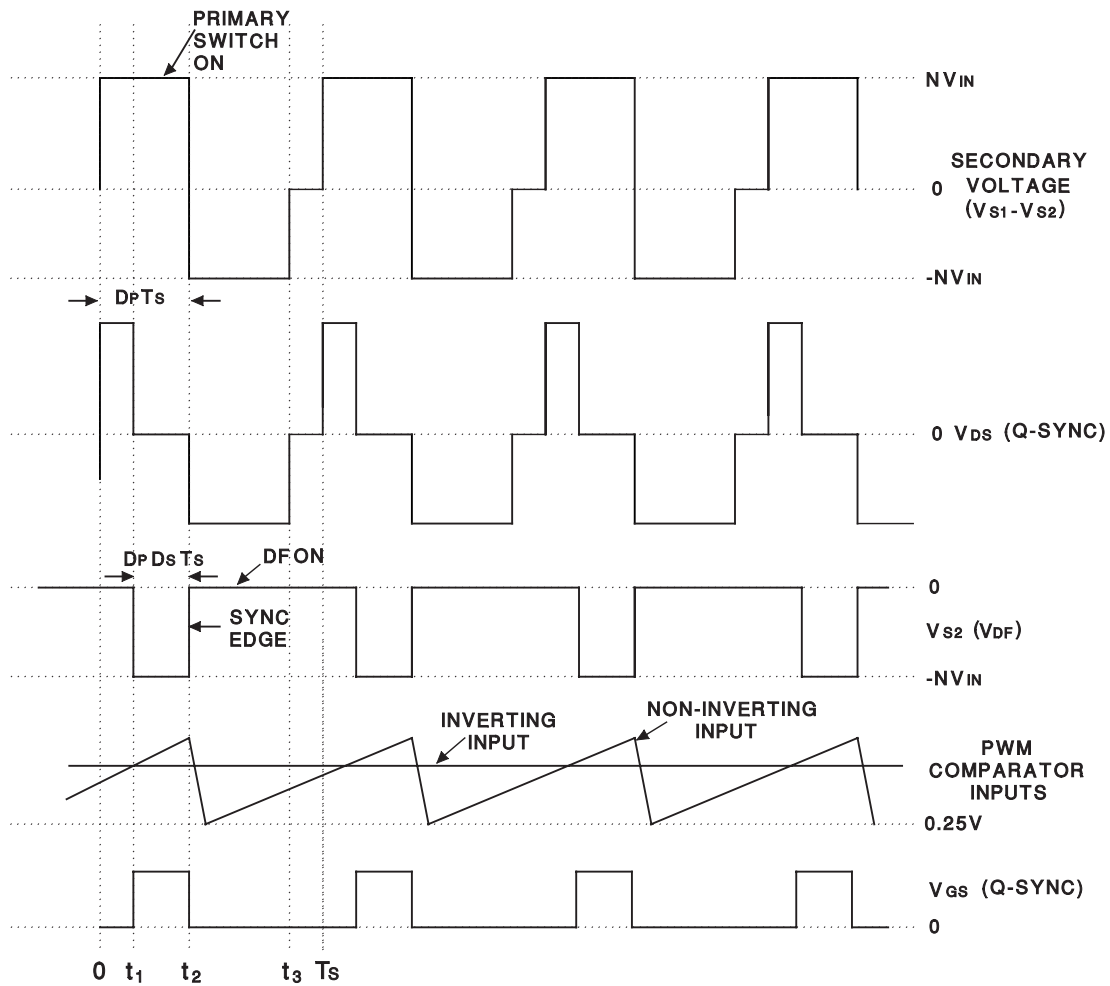
When the synchronizing signal is available, the oscillator frequency should be programmed to be lower than the synchronizing frequency to ensure proper operation. A large difference in self-running and synchronizing frequencies leads to smaller ramp amplitude and higher noise sensitivity. The ramp capacitor is discharged when the synchronization signal arrives and begins charging when the low threshold is crossed.

There are two methods to synchronize to the secondary pulse. One method is to use the rising edge of the secondary pulse, which reduces the maximum duty cycle available. Subsequently, the post regulator switch cannot be turned on during the CT discharge time. The other method is to use the falling edge of the secondary pulse for synchronization. This method is preferable because it allows a slower discharge of the ramp capacitor without affecting the maximum available duty cycle of the post regulator. The UCC3583 SYNC input needs to reach a fixed threshold (1.0V typical) for synchronization to take effect. Hence the IC is usable with either method of synchronization. However, the UCC3583 oscillator configuration is better suited for synchronization to the falling edge. A recommended method to implement the synchronization is shown in Figure 6. By connecting SYNC to a resistive divider between REF and the secondary terminal S2, the synchronization is achieved whenever the voltage on S2 goes from a negative value to zero. RA and RB should be selected so that the voltage on the SYNC pin varies from 0V to 1V. Placement of a Schottky diode from SYNC to COM prevents the voltage at SYNC from going negative. The internal hysteretic SYNC comparator has an inverting input set to 0.5V with about ±0.5V hysteresis.

PWM Comparator

The UCC3583 uses a leading edge PWM scheme. In a leading edge PWM, the output pulse (gate signal) is turned on when the error amplifier crosses the PWM ramp and turned off by the clock/oscillator. Leading edge modulation is naturally provided by magamp type post regulators and is an essential feature for post regulators. Without the leading edge modulation in a multiple output

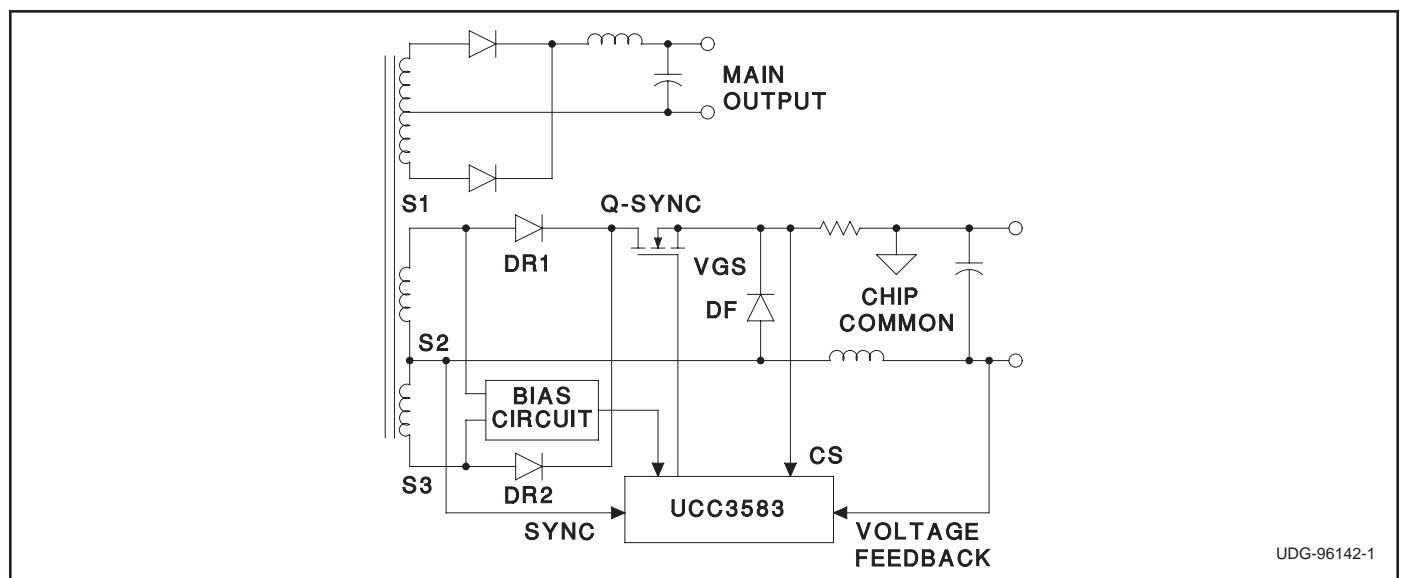
APPLICATION INFORMATION (cont.)



Note: All waveforms are referenced to chip common.

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Figure 2. Single ended post regulator waveforms.



UDG-96142-1

Figure 3. Half-bridge synchronous post regulator application.

APPLICATION INFORMATION (cont.)

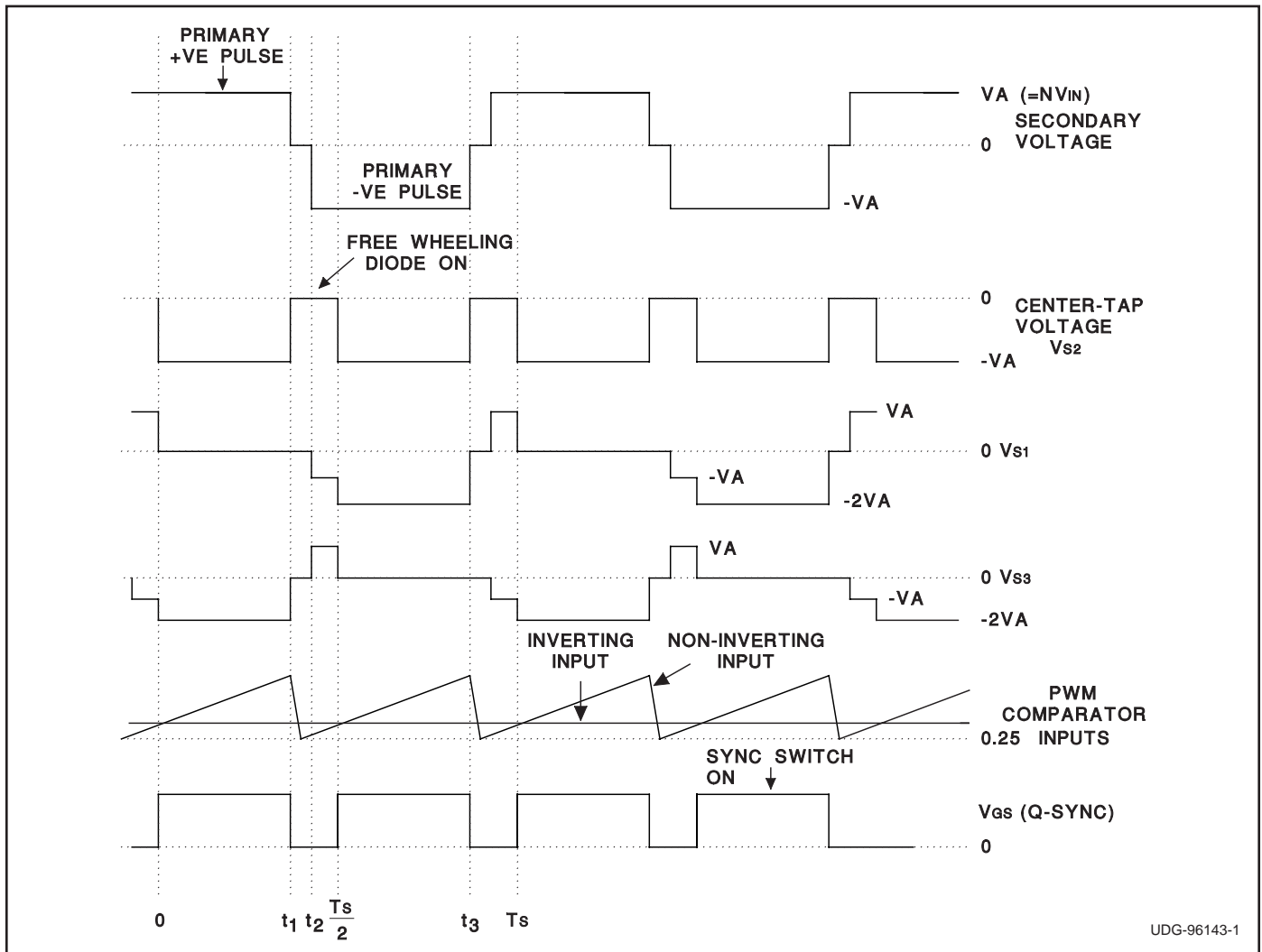


Figure 4. Half-bridge synchronous post regulator to waveforms.

APPLICATION INFORMATION (cont.)

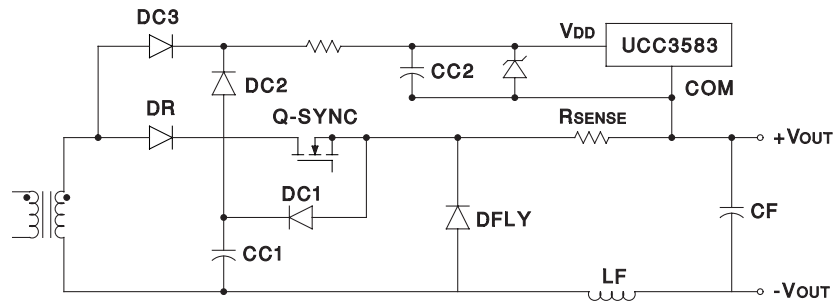


Figure 5a

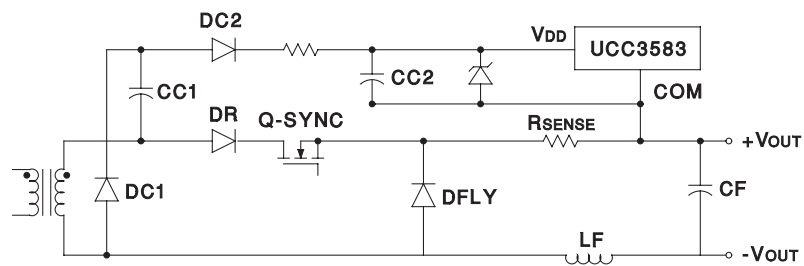
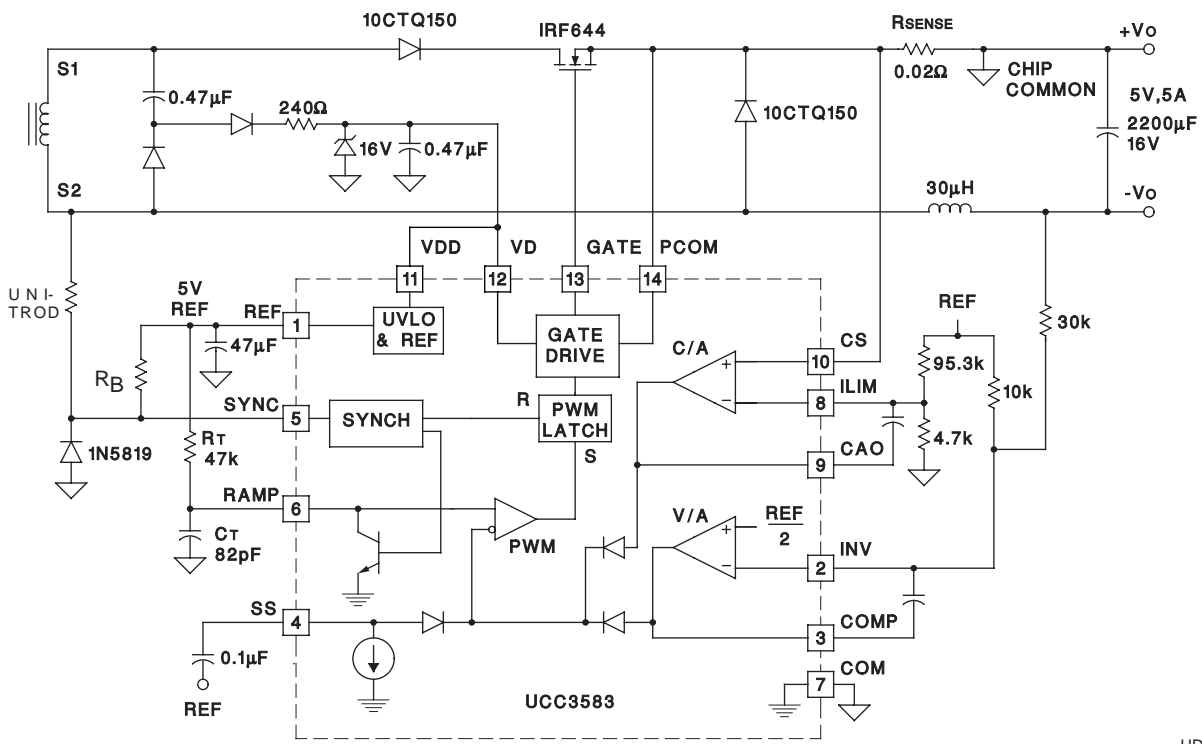


Figure 5b

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Figure 5. Possible implementation for floating bias voltage generation.



UDG-96072-2

Figure 6. Typical application circuit.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
UCC2583D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UCC2583D	Samples
UCC2583DG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UCC2583D	Samples
UCC2583DTR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UCC2583D	Samples
UCC2583DTRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UCC2583D	Samples
UCC2583N	ACTIVE	PDIP	N	14	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	-40 to 85	UCC2583N	Samples
UCC2583NG4	ACTIVE	PDIP	N	14	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	-40 to 85	UCC2583N	Samples
UCC2583QTR	ACTIVE	PLCC	FN	20	1000	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 85	UCC2583Q	Samples
UCC2583QTRG3	ACTIVE	PLCC	FN	20	1000	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 85	UCC2583Q	Samples
UCC3583D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	UCC3583D	Samples
UCC3583DG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	UCC3583D	Samples
UCC3583DTR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	UCC3583D	Samples
UCC3583DTRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	UCC3583D	Samples
UCC3583N	ACTIVE	PDIP	N	14	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	0 to 70	UCC3583N	Samples
UCC3583NG4	ACTIVE	PDIP	N	14	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	0 to 70	UCC3583N	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UCC2583DTR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
UCC3583DTR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
UCC2583DTR	SOIC	D	14	2500	367.0	367.0	38.0
UCC3583DTR	SOIC	D	14	2500	367.0	367.0	38.0

N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS **	14	16	18	20
DIM				
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



14/18 Pin Only
20 Pin vendor option

4040049/E 12/2002

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 - The 20 pin end lead shoulder width is a vendor option, either half or full width.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



4040047-5/M 06/11

NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE

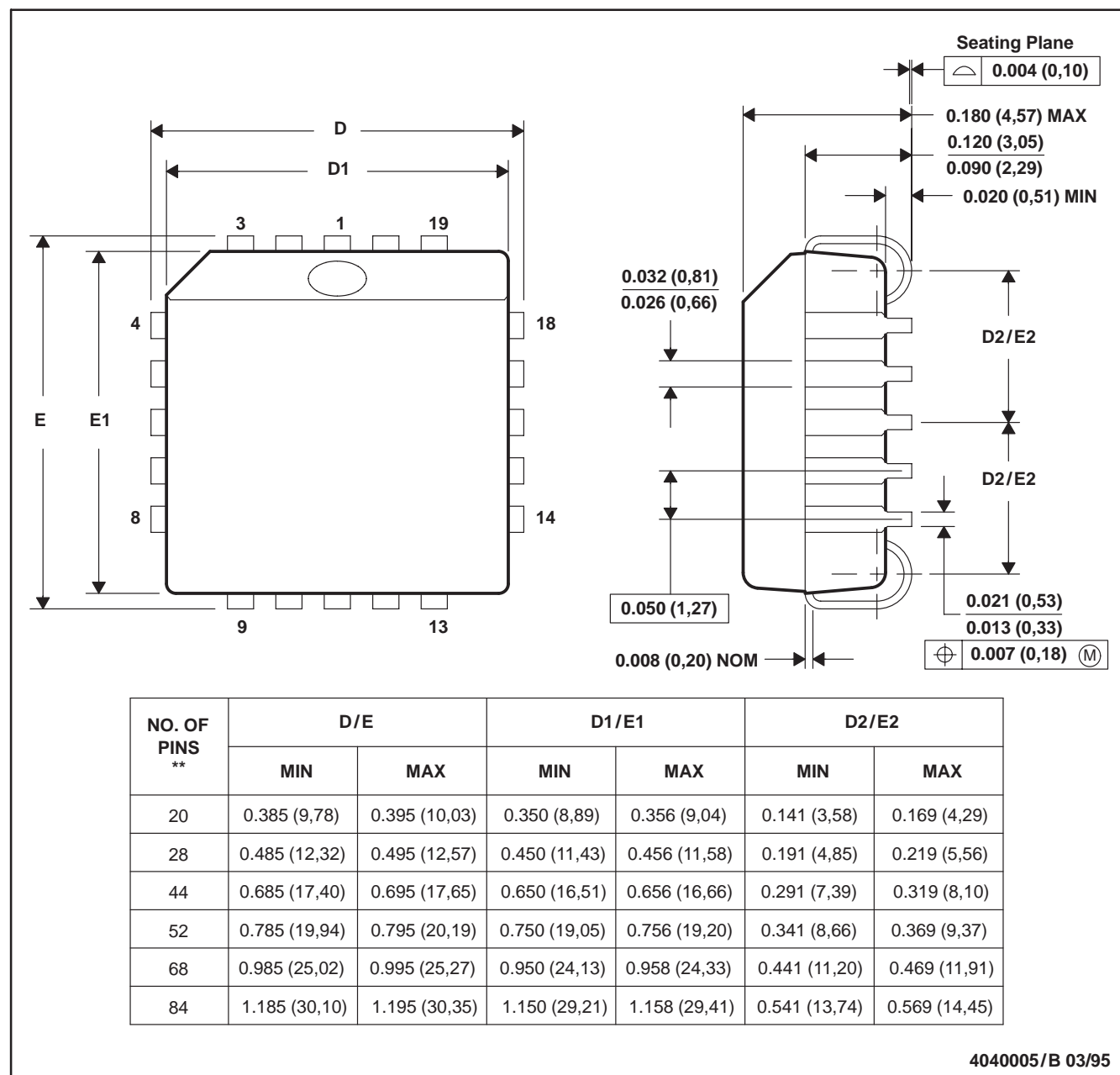


- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

FN (S-PQCC-J**)

PLASTIC J-LEADED CHIP CARRIER

20 PIN SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Falls within JEDEC MS-018

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